## Takashi OHSAWA - Divisional of 09/917,777

## **IN THE SPECIFICATION**

Page 1, immediately after the title, insert as a new paragraph -- This application is a now U.S. Patant No. 6, 621,725 divisional of U.S. Patent Application Serial No. 09/917,777, filed July 31, 2001, the entire contents of which are incorporated herein by reference.--

On page 3, the paragraph beginning at line 17, has been amended as follows:

In order to accomplish the aforementioned and other objects, according to one aspect of the present invention, a semiconductor memory device <u>including at least one transistor</u> in which one bit memory cell is composed of one transistor, wherein the transistor comprises: